

NPN General-Purpose Amplifier

MPSA05

Features

- This Device is Designed for General-Purpose Amplifier Applications at Collector Currents to 300 mA
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CEO}	Collector-Emitter Voltage	60	V	
V _{CBO}	V _{CBO} Collector-Base Voltage		٧	
V _{EBO}	Emitter-Base Voltage	4.0	V	
I _C	I _C Collector Current – Continuous		mA	
T _J , T _{STG}	T _J , T _{STG} Junction and Storage Temperature		°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

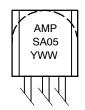
Symbol	Parameter	Max.	Unit
P _D	Total Device Dissipation	625	mW
	Derate Above 25°C	5.0	mW/°C
$R_{ heta JC}$	Thermal Resistance, Junction-to-Case	83.3	°C/W
$R_{ heta JA}$	Thermal Resistance, Junction-to-Ambient	200	°C/W



- 1. Emitter
- 2. Base
- Collector

TO-92-3 CASE 135AR Bent Lead Tape & Reel

MARKING DIAGRAM



A = Assembly Location

MPSA05 = Specific Device Code

Y = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping [†]
MPSA05RA	TO-92 3L	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

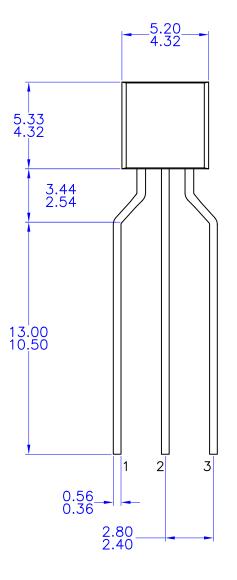
Symbol	Parameter	Conditions	Min.	Max.	Unit
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage (Note 1)	I _C = 1 mA, I _B = 0	60	_	V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	4	-	V
I _{CEO}	Collector Cut-Off Current	V _{CE} = 60 V, I _B = 0	-	0.1	μА
I _{CBO}	Collector Cut-Off Current	V _{CB} = 60 V, I _E = 0	-	0.1	μА
h _{FE}	DC Current Gain	I _C = 10 mA, V _{CE} = 1.0 V	100	-	
		I _C = 100 mA, V _{CE} = 1.0 V	100	-	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 100 mA, I _B = 10 mA	-	0.25	V
V _{BE} (on)	Base-Emitter On Voltage	I _C = 100 mA, V _{CE} = 1.0 V	-	1.2	V
f _T	Current Gain – Bandwidth Product	I _C = 10 mA, V _{CE} = 2 V, f = 100 MHz	100	-	MHz

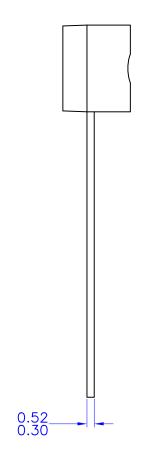
^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

TO-92 3 4.83x4.76 LEADFORMED

CASE 135AR ISSUE O

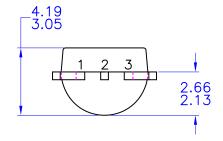
DATE 30 SEP 2016





NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994



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